Diffusion Studies in Mg-Al-Zn



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Collaborations and Coordination





 To develop a Mg tracer diffusion database for Mg, Zn, Al in magnesium-rich alloys for incorporation in the Integrated Computational Engineering (ICME) project

Approach/Strategy

- Measure tracer diffusion coefficients of Mg and Zn in the Mg-Al-Zn-Mn system using secondary ion mass spectrometry (SIMS)
- Tracer diffusion data are preferred for database incorporation: robust, accurate, assumption-free, easier to utilize
- In case of a monoisotopic element such as AI, interdiffusion data will be combined with measured tracer diffusivities along with thermodynamics to extract tracer coefficients using diffusion theory (e.g., Darken/Manning theories)



Onsager Diffusion Formalism

- Intrinsic fluxes where driving forces are chemical potential gradients (Onsager): $J_k = -\sum_i L_{ki}^n \operatorname{grad}(\mu_i) \qquad \sum_k J_k = -J_v$
- L_{ki}'s obtained from tracer diffusion data using Manning relations:

$$L_{ii} = \frac{C_i D_i^*}{kT} \left(1 + \frac{2C_i D_i^*}{M_0 \sum_k C_k D_k^*} \right) \qquad L_{ij} = \frac{2C_i D_i^* 2C_j D_j^*}{kT M_0 \sum_k C_k D_k^*} \qquad i \neq j$$

- Chemical potentials from thermodynamic database
- Cross-terms are not ignored as in Darken (correlation effects influence cross-terms)
- Tracer diffusion data is independent of thermodynamic database



Tracer Diffusion

Data over large temperature range



1D Theory

Slab diffusing into material (constant D)

$$C(x,t) - C_1 = \frac{(C_0 - C_1)}{2} \left[\operatorname{erf}\left(\frac{x+h}{2\sqrt{Dt}}\right) - \operatorname{erf}\left(\frac{x-h}{2\sqrt{Dt}}\right) \right]$$
$$C(x,t) - C_1 \approx (C_0 - C_1) \frac{h}{\sqrt{\pi Dt}} \exp\left(-\frac{x^2}{4Dt}\right) \qquad h << 2\sqrt{Dt}$$

$$\begin{array}{c} 0.1 \\ 0.01 \\ 0.01 \\ 0.001 \\ 0.0001 \\ 0.0001 \\ 0 \\ 0 \\ 0 \\ 0 \\ 0 \\ 1 \\ 2 \\ 3 \\ 4 \\ 5 \\ 0 \\ 0 \\ 0 \\ 0 \\ 1 \\ 2 \\ 3 \\ 4 \\ 5 \\ 6 \\ \hline Depth (mm) \\ \end{array}$$

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²⁵Mg tracer on Mg at 300°C 1 → ← 0.1µm *t* (hr) 0.5 0 C(x,t)-0.1 0.3 0.4 -1.6 0.2 *C*₁=0.1 0.1-1 2 3 5 0 4 6 Depth (µm)

$$h \leftarrow C_1$$

Mg Abundances					
Isotope	²⁴ Mg	²⁵ Mg	²⁶ Mg		
Natural	0.7899	0.1001	0.1100		
Tracer	0.0180	0.9787	0.0033		



Angle polish SIMS for shallow or deep diffusion depths



d = t / sin(θ) : angle polish surface used for SIMS discrete/depth profile measurements t = 100 µm: tracer diffusion depth θ = 1 deg; d = 5730 µm; Magnification = 5730 /100 ~ 57 Hence, 5730/20 ~ 286 discrete SIMS measurements every 20 µm along d

Tracer Diffusion: SIMS-based thinfilm stable-isotope technique



(1) Prepare single phase alloy sample (e.g., Mg-5%Al) at T_o



(2) Deposit thin film (100 nm) of stable isotope of an alloy element (e.g., Mg²⁶) on annealed sample (3) Anneal at T_o for desired times (mins to hrs) to cause isotope to diffuse inwards

(3)





Process Sequence

- **1.** Single phase alloy extrusion
- 2. Homogenization and graingrowth anneal
- **3.** Sectioning
- 4. Conditioning anneal
- 5. Polishing/Coating
- 6. Annealing
- 7. SIMS profiling
- 8. Analysis

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0.025

0.015

0.010

0.005

0.000

-0.005

0 1 2 3 4 5 6 7 8

Depth (µm)

S 0.020

10 11 12 13 14 15

0.005

0.004

0.003

0.002

0.001

0.000 sidual

-0.001

-0.002

-0.003

0.004

-0.005

Diffusion annealing technique



Design allows rapid heating (Cu block, fin design) and cooling (liquid nitrogen)

- Mg capsule & turnings act as natural getter to prevent oxidation
- Thermocouple in capsule allows full correction and more accurate analysis especially for short anneal times (10 minutes)



Secondary Ion Mass **Spectrometry**

- **Roughness increases with sputter** depth for polycrystalline samples due to grain orientation
- Oxygen leak creates an amorphous oxide surface to reduce grain orientation effects
- Also, energy and angle are optimized to reduce roughness

			Roughness,	
Energy, kV	O-leak	Angle	nm	
Unsputtered			7.2	
3	yes	37	10.7	
2	yes	40.6	10.7	Optimized
3	yes	40.6	12.2	
3	yes	46	17.4	
3	no	46	30.7	
5	no	44	37.7	🗕 Typical





Experimental Mg self-diffusion



Annealing produces large grains



Electron Backscatter Diffraction (EBSD) map (inverse pole figure – top right) of grain orientations in a pure polycrystalline Mg rod after annealing treatment. *left*: Identical grain structure map with enhanced contrast.

Optimized SIMS profiles within single grains yield more accurate bulk diffusivities



Fitting of diffusion depth profiles

Example: SIMS measured excess 25Mg tracer after 350°C ~1hr



Replace concentration with abundance:
$$C(x,t) - C_1 = \frac{(C_0 - C_1)}{2} \left[erf\left(\frac{x+h}{2\sqrt{Dt}}\right) - erf\left(\frac{x-h}{2\sqrt{Dt}}\right) \right]$$

Nonlinear fit of *D*, *h* and *A* by minimizing the sum of the square of the residuals:





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Temperature profile correction

- Effective time at annealing temperature can be calculated using the actual profile and the activation energy (Rothman 1984) using numerical integration
- Capsule design allows rapid change and real-time temperature measurement for precise correction, even for times < 10 minutes
- Example shows 8.6% correction for Mg at 475°C for ~10 minutes

$$t_{\text{effective}} = \int \exp\left[-\frac{Q}{R}\left(\frac{1}{T(t)} - \frac{1}{T_{\text{anneal}}}\right)\right] dt$$





Mg self-diffusion



Spread in fitted diffusivities and comparison of orthogonally cut samples, annealed <u>together</u> at each temperature

T(°C)	s.d. (%)	Max- Min (%)	s.d. (%)	Max- Min (%)	D <u>⊥</u> - D (%)
	⊥ C-axis		C-axis		
475	0.8	1.1	-	-	-
400	3.2	6.4	1.6	3.1	13.3
350	2.4	4.9	7.7	14.6	14.2
300	5.5	10.3	9.3	20.8	-11.2
250	14.5	20.5	-	-	-

Experimental results consistent with polycrystalline radiotracer measurements
 Tracer diffusivities in directions parallel to rod axis (⊥C-axis) are typically higher compared to diffusivities normal to rod axis (|| C-axis)



Mg Isotope Comparison

- $A_i(x)$ measured abundance $f(x) = \frac{A_i(x) - B_i}{T_i - B_i} \qquad \begin{array}{c} B_i \\ B_i \\ T_i - \text{tracer abundance} \\ T_i - \text{tracer abundance} \end{array}$
- Alternative fitting determines the tracer concentration using each isotope
- The SIMS instrumental bias for each isotope is fully corrected to obtain the abundances with depth, $A_i(x)$ for each isotope i
- Fit of *D* & *h* performed
- Small trend observed in D with isotope mass - i.e., lower D with increasing mass

Minimize D, h for each isotope i:



$$\sum_{x} \left\{ \frac{A_{i}(x) - B_{i}}{T_{i} - B_{i}} - \frac{1}{2} \left[\operatorname{erf} \left(\frac{x + h}{2\sqrt{Dt}} \right) - \operatorname{erf} \left(\frac{x - h}{2\sqrt{Dt}} \right) \right] \right\}^{2}$$

Isotope Effect?

• Trend for slightly lower diffusivity with isotope mass



Diffusion length $\sqrt{4Dt}$ with thermal velocity $\sqrt{2Rt/m}$



Mg tracer diffusion in polycrystalline Mg-Al-Zn alloys

Setup for thin film sputter deposition on Mg alloy samples.

Mg tracer diffusivities as a function of reciprocal temperature for pure Mg and three Mg alloys (Wt %)



D (cm²/s)







Fitting example

 Fitting excludes the Mg-rich zone near the surface



Example: Self diffusion of Mg in MZ3



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Zn Diffusion

- Pure zinc has a high vapor pressure and would evaporate even at 270°C (~450nm/min)
- Solution: Drive in Zn at 200°C (loss rate of ~5nm/min) to ~100nm, then anneal at diffusion temperature
- Zinc is only weakly soluble in Mg at low temperatures and forms a number of compounds Mg_xZn_y
- Holdup region near surface but good fit in dilute region



Interdiffusion Studies in Mg-Al-Zn



MA1

Selected diffusion couples in hcp Mg-Al-Zn for interdiffusion studies

Interdiffusion data combined with measured Mg tracer (this work) and thermodynamic data (Φ) is used to compute unknown AI tracer diffusivity using diffusion theory (Darken-Manning relations)



 D_{inter} (Mg s.s.) = [$X_{Mg} D_{AI}^* + X_{AI} D_{Mg}^*$] $\Phi * S$ Manning relation in binary Mg-AI

ORNL Diffusion website

Note: The contents of this website are confidential and are restricted to the collaborato associates. The contents are for their personal use and may not be distributed without Site hosted by Oak Ridge National La	Page 1 of 4 rs listed below and to their in-house permission of the PI. aboratory / Disclaimers / <i>Contact the webmaster</i> c	 <u>http://www.ornl.gov/sci/diffusion</u> (private)
Isotopic Diffusion Databases for Magnesium Integrated Computational Materials Engineering (Mg-ICME)	NATIONAL LABORATORY elle for the department of energy	Page 1 of 1
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http://www.oml.gov/sci/diffusion/index.html	2/29/2012	

Future Work

- Continue Mg, Zn tracer diffusion experiments and analysis in Mg-Al-Zn-Mn alloys
- Interdiffusion measurements using incremental diffusion couples in Mg-Al-Zn-Mn alloys to extract Al, Mn tracer diffusivities
- Mg, Nd, Ce tracer diffusion studies in Mg-Al-Nd, Ce alloys (only preliminary data likely)
- Initiate experimental work on continuously selectable alloys (co-sputtered) and grain-boundary diffusion
- Ongoing theoretical grain-boundary studies



Alloy film magnetron co-sputtering for Mg-alloys & compounds

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- Multiple source sputtering system to produce continuously variable alloys and films for grain-boundary studies
 - Uniform composition
 - Wedge variable composition
- Tracer-film deposition in situ
- Substrate heating
- UHV base pressure of 10⁻⁹ Torr
- Load lock sample exchange



²Magnetron Co-sputtering System

Grain boundary diffusion using thin films

- The proportion of diffusion due to bulk and boundary effects can be controlled through grain size
- Grain size is generally pinned by top and substrate boundaries to be ~2X the thickness of annealed thin films
- Co-deposition of Mg, AI and Zn produces variety of alloy films for diffusion studies









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Relevance

 A tracer diffusion database in Mg alloys is of fundamental importance to the ICME and other integrated materials design efforts (e.g., Materials Genome Initiative) in establishing design and modeling tools, optimizing manufacturing processes, and predicting performance requirements.

Key accomplishments/progress

- Established SIMS based tracer diffusion technique
- Obtained Mg self-diffusivities in pure polycrystalline Mg samples using our SIMSbased thin-film stable-isotope technique, validating and extending historic radiotracer measurements to lower temperatures.
- Obtained Mg & Zn tracer diffusivities in a number of alloys in the Mg-Al-Zn system.
- Developed a superior annealing technique for Mg based on the Shewmon-Rhines approach.
- Diffusion website facilitates communication between local and international collaborators, and served as a repository for data, experiments, analysis, theory and relevant literature.

